

#### Technical Data Data Sheet N0412, Rev. A

SDURF2060CT

Green Products

# SDURF2060CT ULTRAFAST PLASTIC RECTIFIER

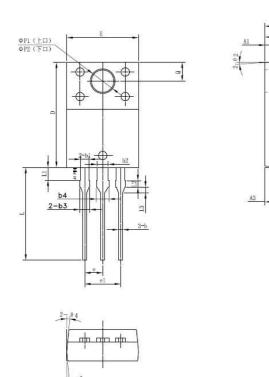
#### **Applications:**

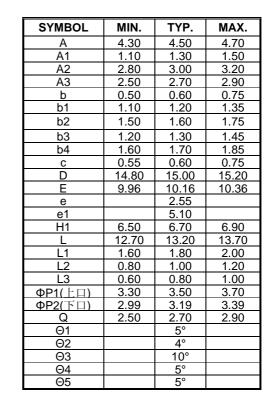
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

#### Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Mechanical Dimensions: In mm**





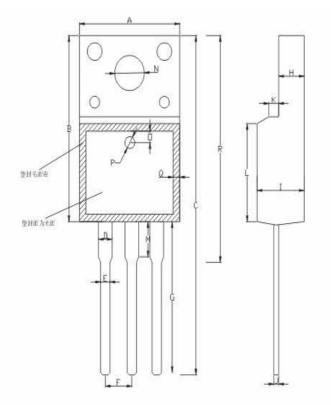
# **OPTION 1(HD)**

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A:10.20	$) \pm 0.50$	B:15.90	$\pm0.50$	C:29.00	$\pm 1.00$	D:1.24	$\pm 0.10$
E:0.80	$\pm 0.10$	F:2.54	$\pm 0.10$	G:13.10	$\pm 1,0$	H:2.55	$\pm 0.05$
I:4.70	$\pm 0.05$	J:0.50	$\pm 0.05$	K:1.20	$\pm 0.20$	L:8.00	$\pm 0.50$
M:3.00	$\pm 0.50$	N:3.20	$\pm 0.20$	O:1,25	$\pm 0.05$	P:1.5	$\pm 0.05$
Q:1.0	±0.20	R:19.2	$\pm 1.0$				

# **OPTION 2(SR)**

### ITO-220AB



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### Marking Diagram:



Where XXXXX is YYWWL

SDUR	= Device Type
F	= Package type
20	= Forward Current (20A)
60	= Reverse Voltage (600V)
СТ	= Configuration
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

# **Ordering Information:**

Device	Package	Shipping	
SDURF2060CT	ITO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	600	V
Average Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=100℃, rectangular wave form	20	А
Peak One Cycle Non- Repetitive Surge Current (Per leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	100	A



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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@10A, Pulse, T <sub>J</sub> = 25°C	2.2	V
	V <sub>F2</sub>	@10A, Pulse, T <sub>J</sub> = 125°C	2.0	V
	I <sub>R1</sub>	$@V_R = rated V_R$	10	μA
Reverse Current*		$T_J = 25^{\circ}C$		
	I <sub>R2</sub>	$@V_{R} = V_{R}$	500	μA
		$T_J = 125^{\circ}C$		
Reverse Recovery Time	t <sub>rr</sub>	$I_F$ =500mA, $I_R$ =1A,and $I_{rm}$ =250mA	50	ns

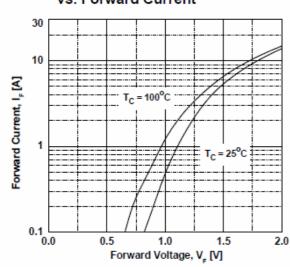
\* Pulse width < 300  $\mu s, \ duty \ cycle < 2\%$ 

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	5.0	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



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#### Figure 1. Typical Forward Voltage Drop vs. Forward Current

Figure 2. Typical Reverse Current vs. Reverse Voltage

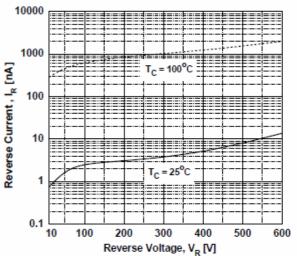


Figure 3. Typical Junction Capacitance

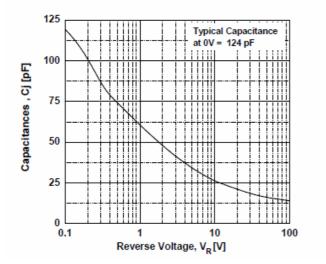
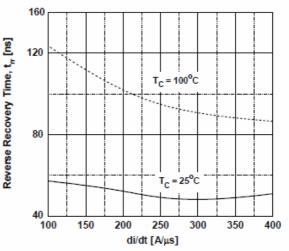


Figure 4. Typical Reverse Recovery Time vs. di/dt





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